

INDIAN INSTITUTE OF TECHNOLOGY BHUBANESWAR



Introduction to Electronics Laboratory

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- **Input characteristics**
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Objective:

- **Measuring Input Characteristics of Common Emitter BJT**
- **Measuring Output Characteristics of Common Emitter BJT**
- **Measuring Transfer Characteristics of Common Emitter BJT**
- **Measuring the Base-Emitter Resistance**
- **Measuring the Output Resistance**
- **Measuring the Early Voltage**
- **Measuring the Transconductance**

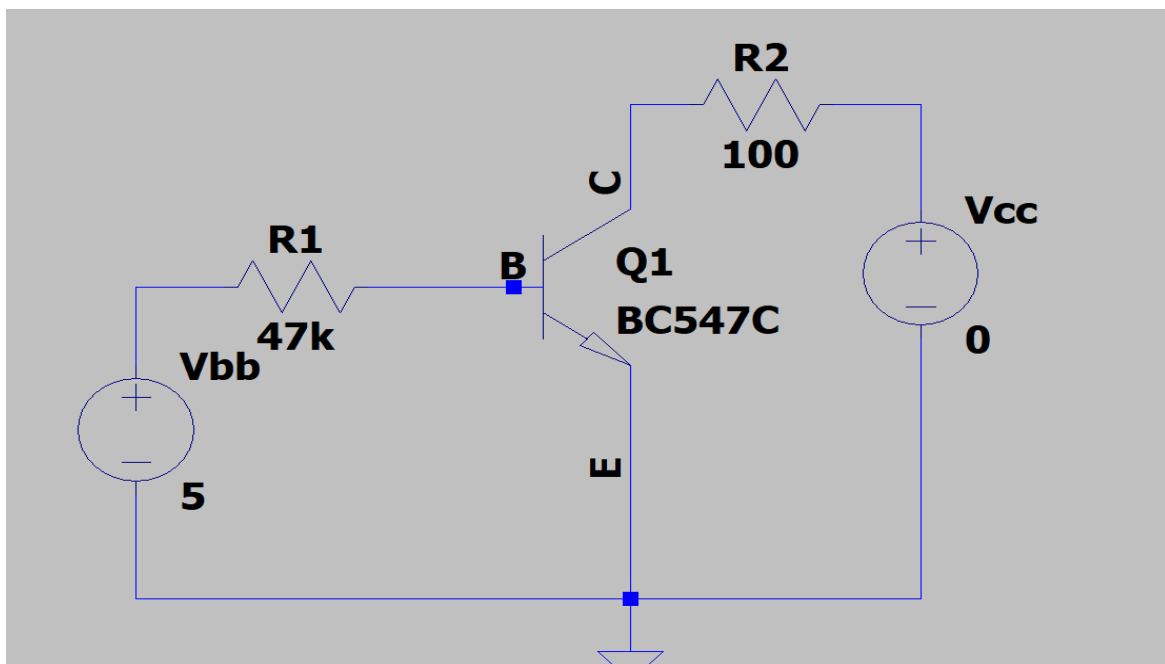
Measuring Input Characteristics:

In this experiment, we will be dealing with Common-Emitter BJT.

$$I_B = I_S e^{V_{BE}/nV_T}, V_T = 26\text{mV}$$

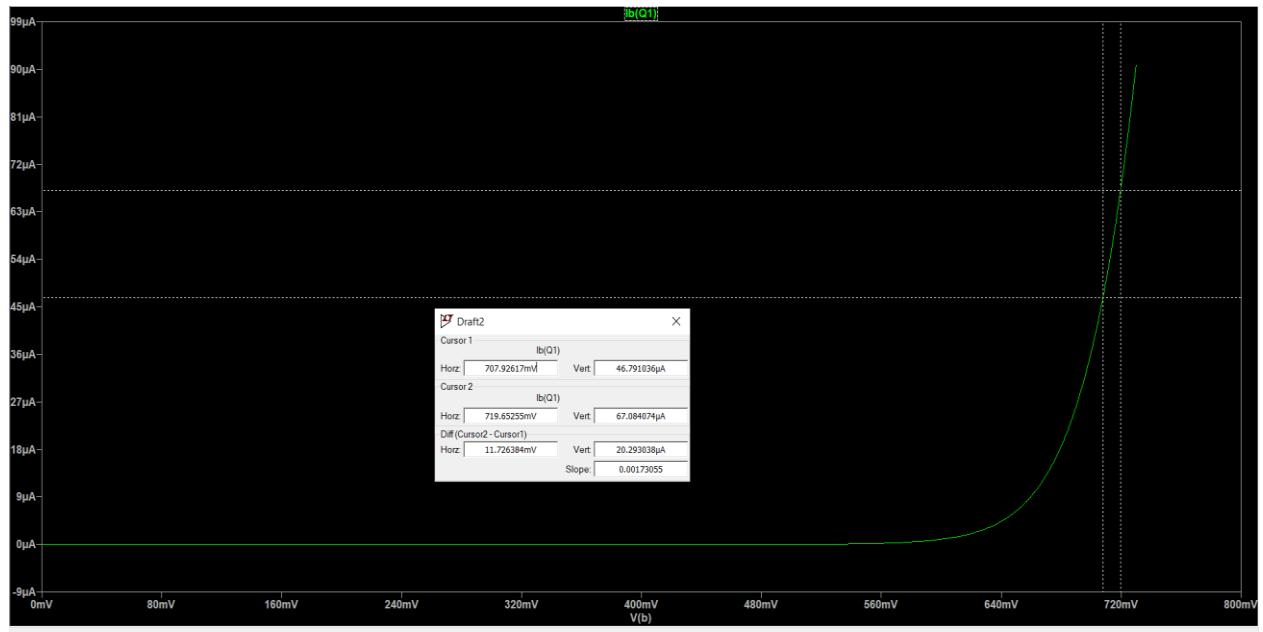
$$\Delta V_{BE}/\Delta I_B = r_{BE} = \text{Base-Emitter Resistance}$$

Circuit Diagram:

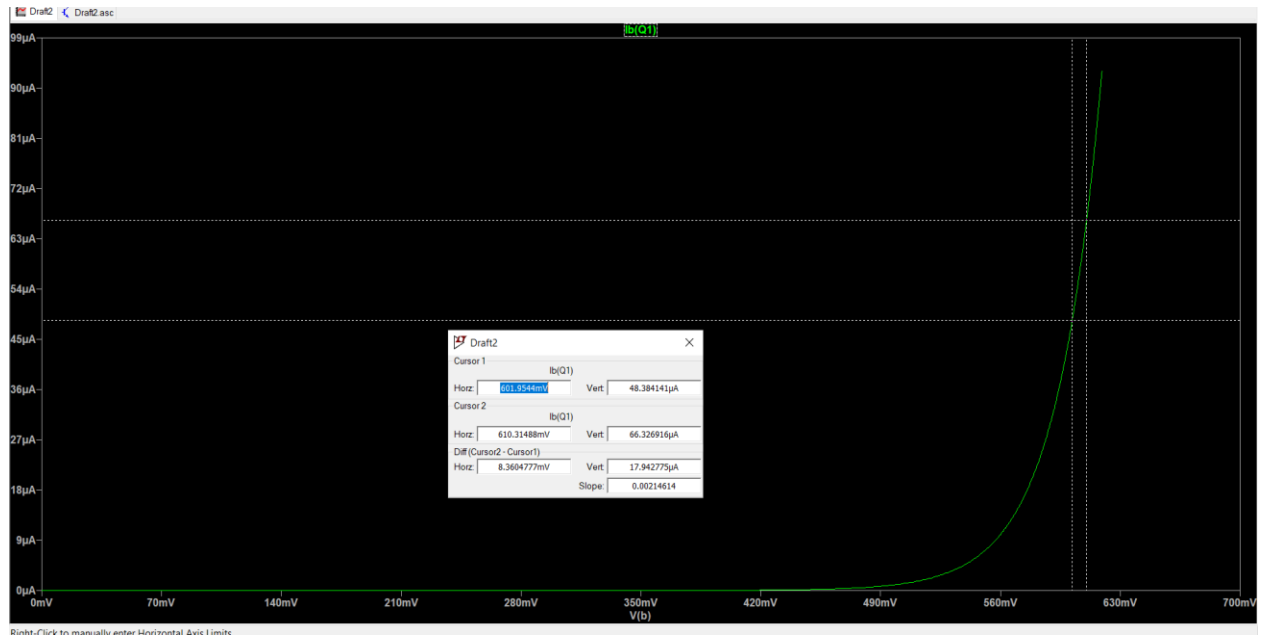


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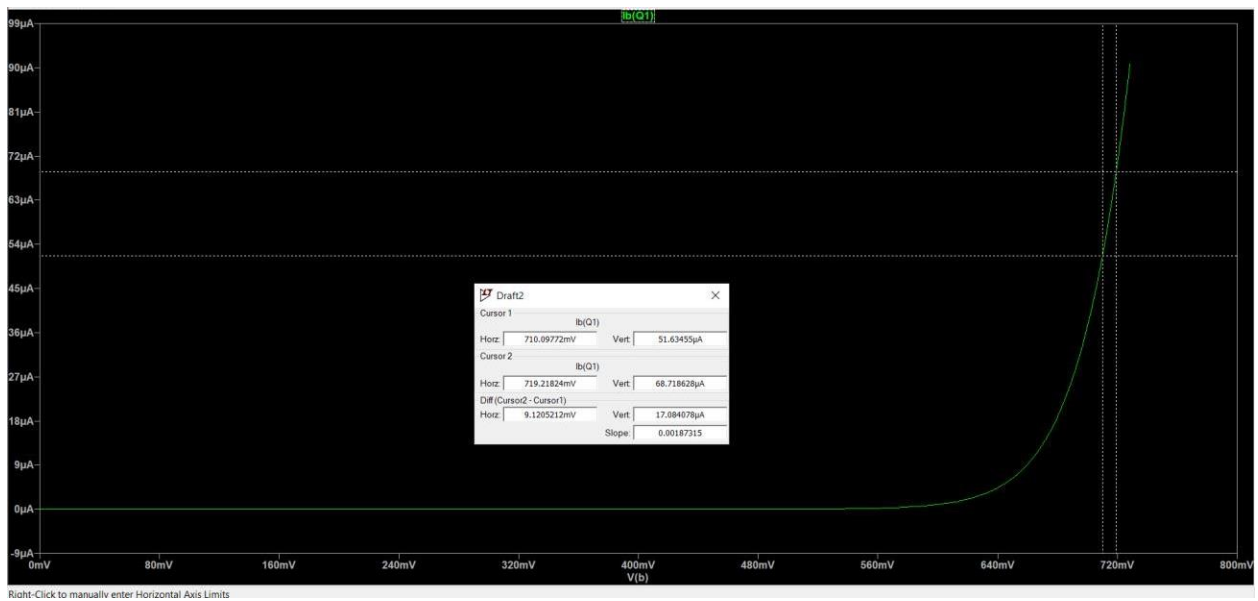
We plotted graph between I_B vs V_{BE} by using DC sweep for V_{BE} and by keeping V_{CC} constant. Here we took 3 different values for V_{CC} .



Here $V_{CC}=20V$ $\Delta V_{BE}=11.726384mV$, $\Delta I_B= 20.293\mu A$ and $\Delta V_{BE}/\Delta I_B= r_{BE1}= 578ohm$.



Here $V_{CC}=0V$ $\Delta V_{BE}= 8.360477mV$, $\Delta I_B= 17.942775\mu A$ and $\Delta V_{BE}/\Delta I_B= r_{BE2}=466ohm$.



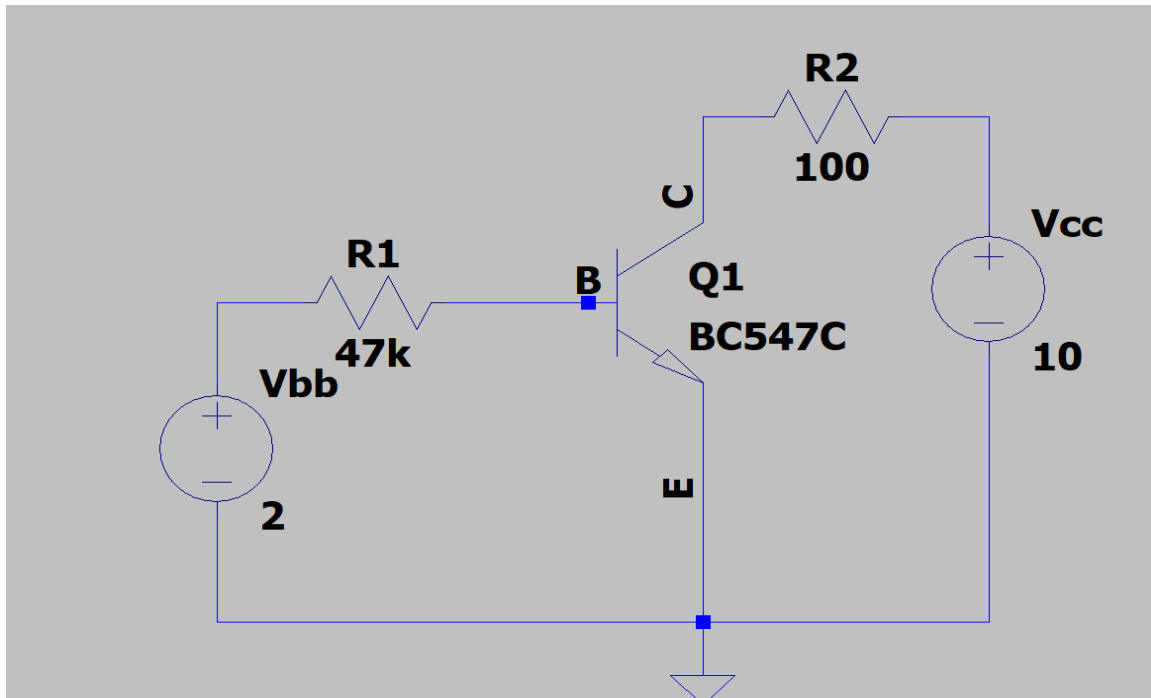
Here $V_{CC}=10V$ $\Delta V_{BE}= 9.12mV$, $\Delta I_B= 17.084\mu A$ and $\Delta V_{BE}/\Delta I_B=r_{BE3}=533.8ohm$.

Measuring Output Characteristics:

$$I_c = I_s e^{V_{be}/nV_t} (1 + V_{CE}/V_A), \quad V_A = \text{Early Voltage.}$$

But ideally V_A is very large. So, $I_c = I_s e^{V_{be}/nV_t}$.

Circuit Diagram:

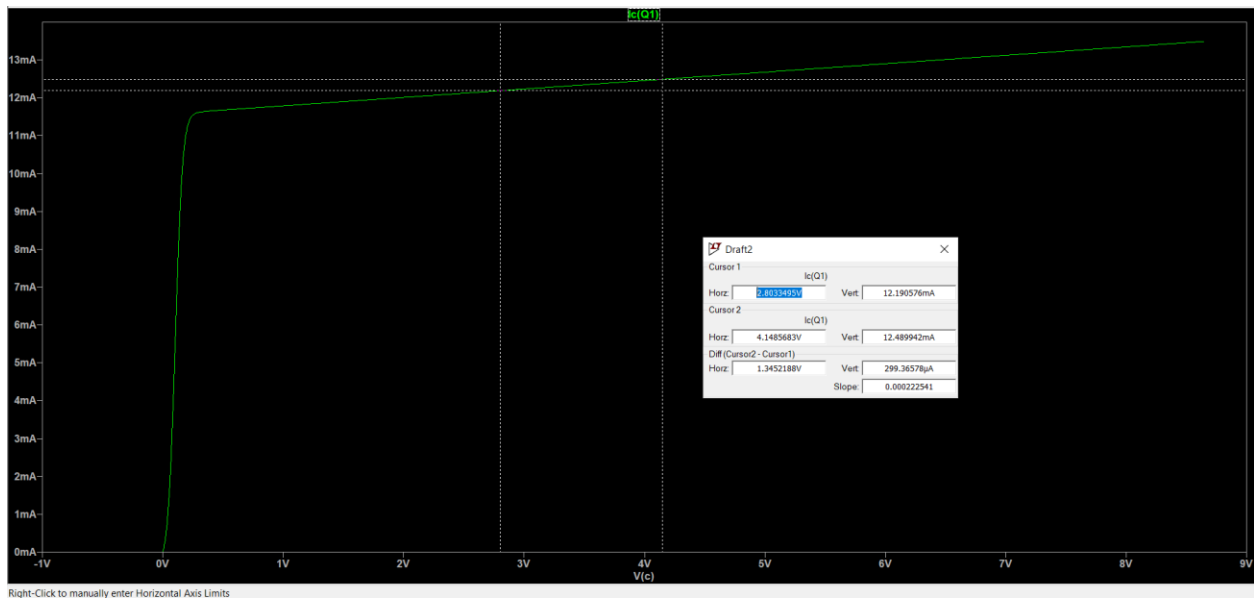
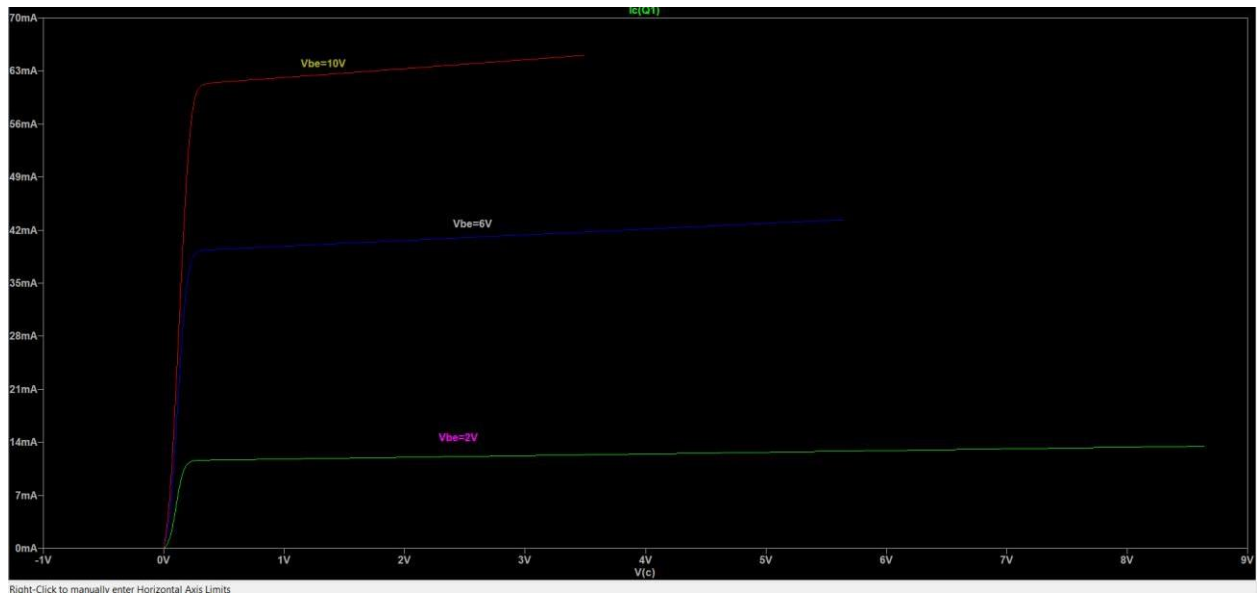


Here we will be using DC sweep for V_{CC} and keep V_{BE} as constant. We will be plotting output characteristics by taking 3 different values for V_{BB} .

And $r_o = \Delta V_{CE} / \Delta I_c = V_A / I_c = \text{output resistance}$.

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I_C vs V_{CE}

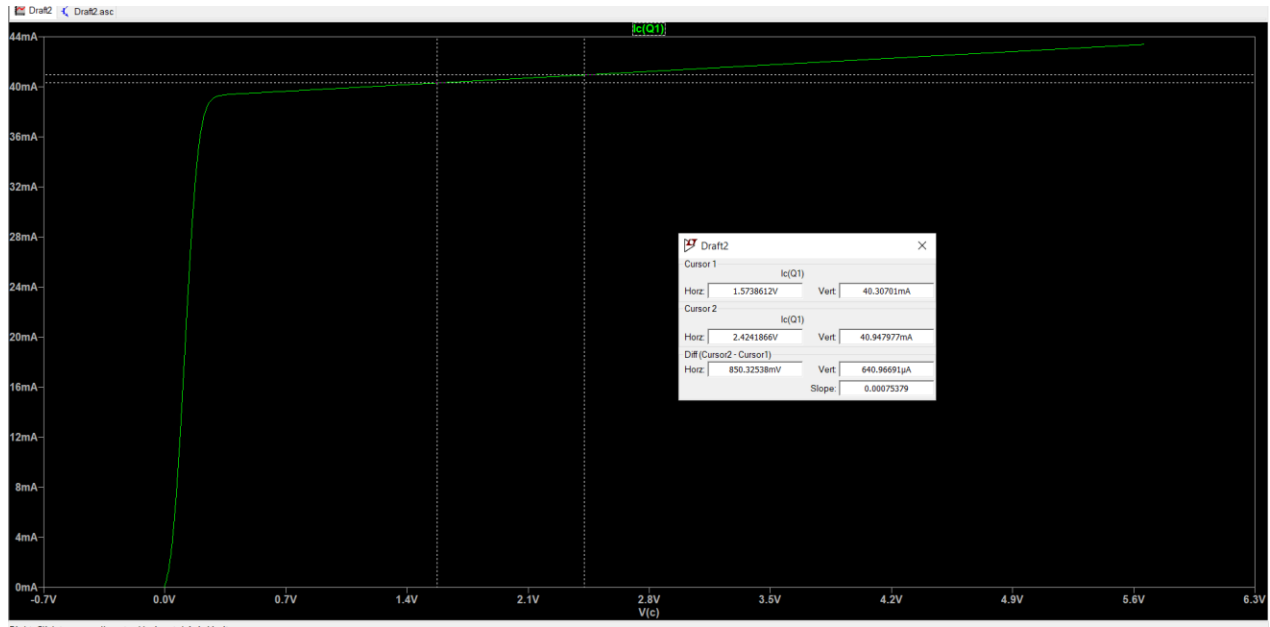


Here $V_{BB}=2V$, $\Delta V_{CE}=1.3452V$, $\Delta I_C=299.365\mu A$ and $\Delta V_{CE}/\Delta I_C = r_o=4493.55\Omega$.

We can measure Early voltage by taking the linear part of the graph.

$I_C - 12.19\text{mA} = \text{slope} \times (V_{CE} - 2.8033\text{V})$ and it cuts x-axis at $-V_A$.

So, by keeping $I_C=0$ we get $V_{CE} = -51.97V$. So, the Early Voltage $V_A = 51.97V$.



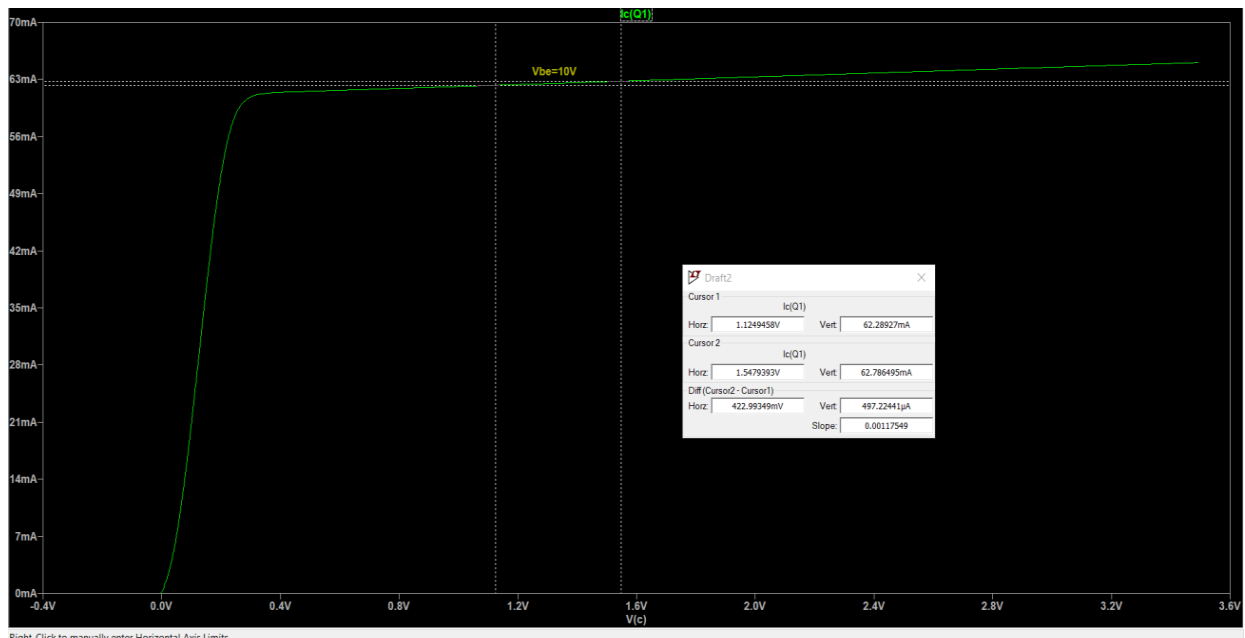
Here $V_{BB}=6V$ $\Delta V_{CE} = 0.85V$, $\Delta I_C = 640.9\mu A$ and $\Delta V_{CE}/\Delta I_C = r_o = 1326.63\Omega$.

We can measure Early voltage by taking the linear part of the graph.

$I_C - 40.307mA = \text{slope} \times (V_{CE} - 1.5738V)$ and it cuts x-axis at $-V_A$.

So, by keeping $I_C=0$ we get $V_{CE} = -51.89V$. So, the Early Voltage $V_A = 51.89V$.

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Here $V_{BB}=10V$ $\Delta V_{CE}= 0.423V$, $\Delta I_C= 497.224\mu A$ and $\Delta V_{CE}/\Delta I_C= r_o= 850.71\Omega$.

We can measure Early voltage by taking the linear part of the graph.

$I_C- 62.289mA = \text{slope} \times (V_{CE} - 1.12V)$ and it cuts x-axis at $-V_A$.

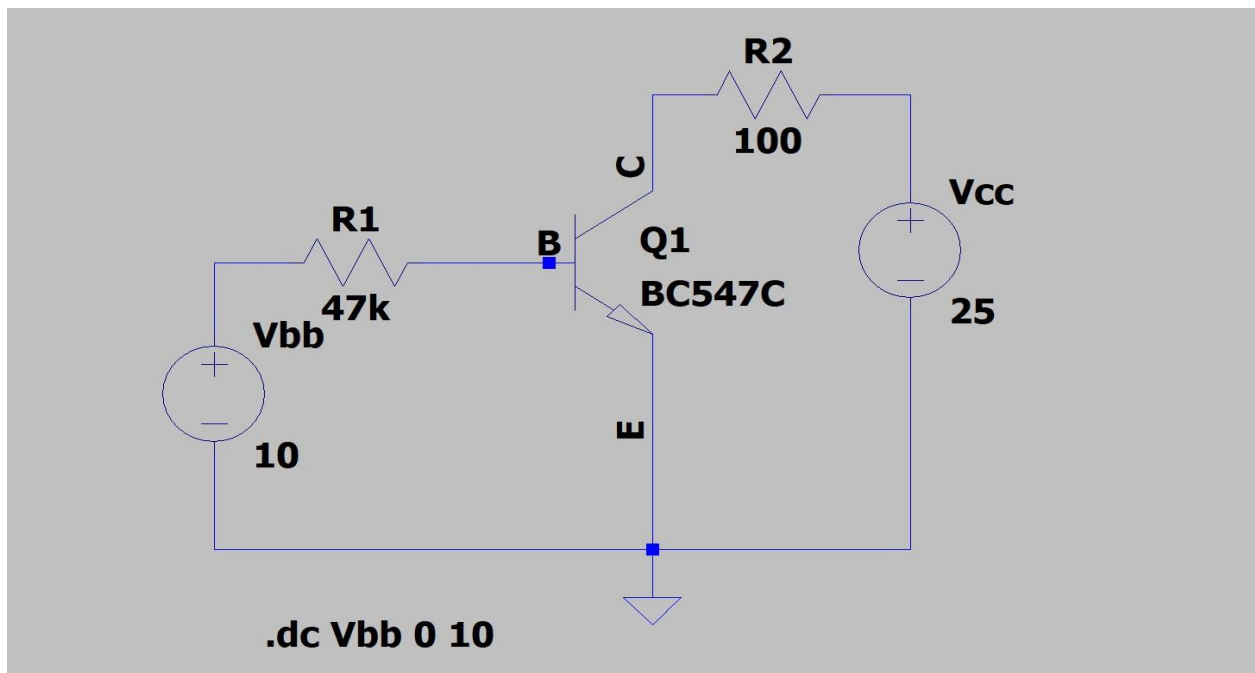
So, by keeping $I_C=0$ we get $V_{CE}= -51.86V$. So, the Early Voltage $V_A= 51.86V$.

Measuring Transfer Characteristics:

Here the plot is between I_C and V_{BE} .

$\Delta I_C / \Delta V_{BE} = g_m = \text{Transconductance}$.

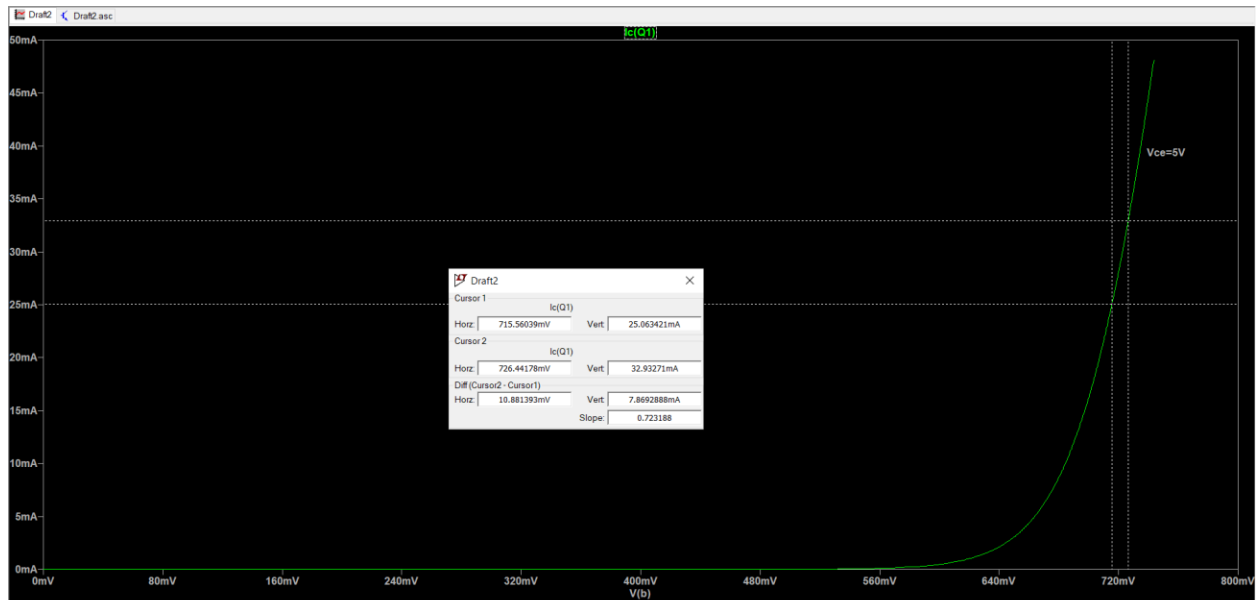
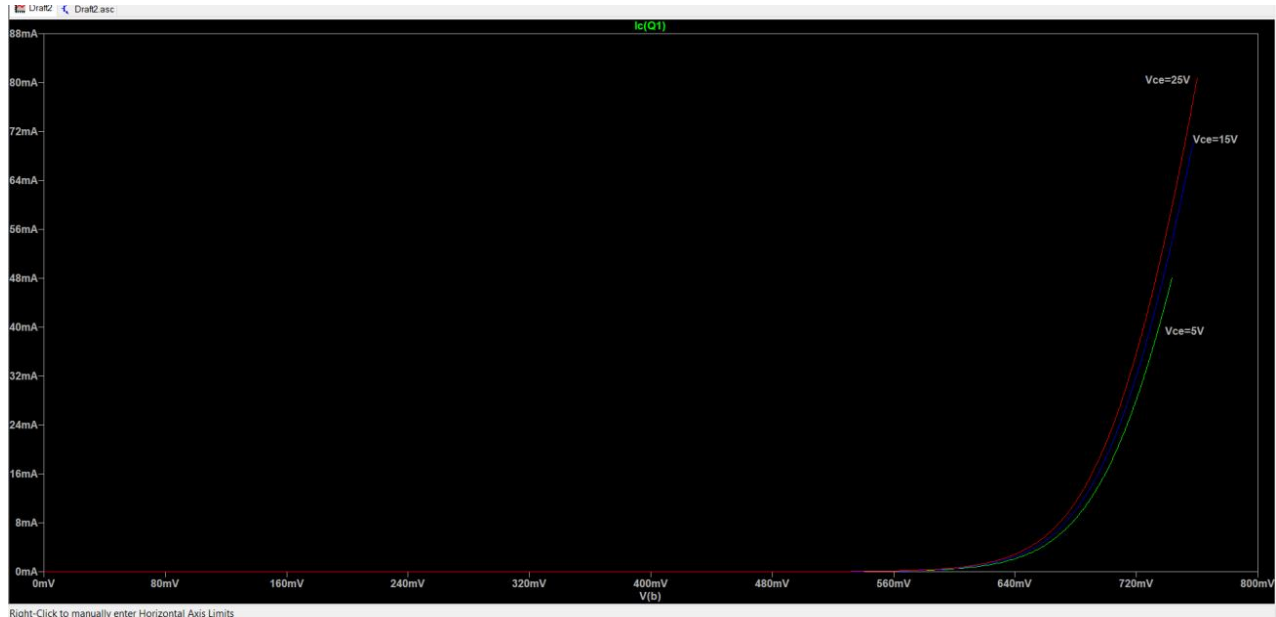
Circuit Diagram:



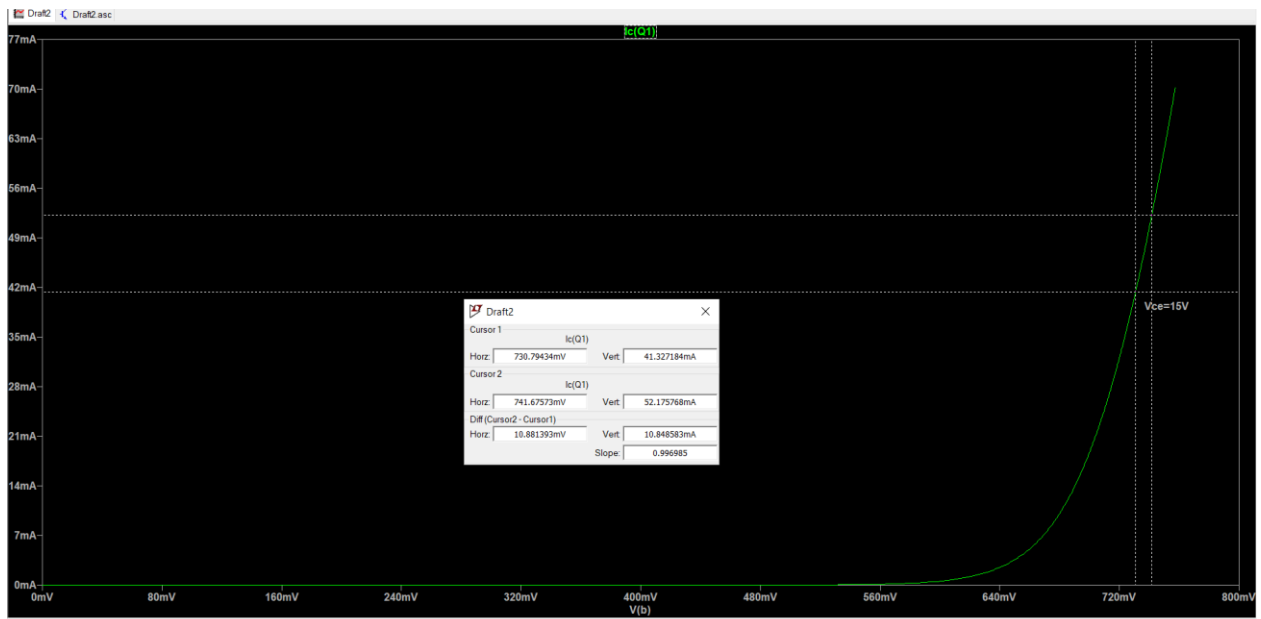
Here we will be using DC sweep for V_{BB} and keeping V_{CE} as constant. We will be plotting transfer characteristics by taking 3 different values of V_{CC} and finding transconductance in each case.

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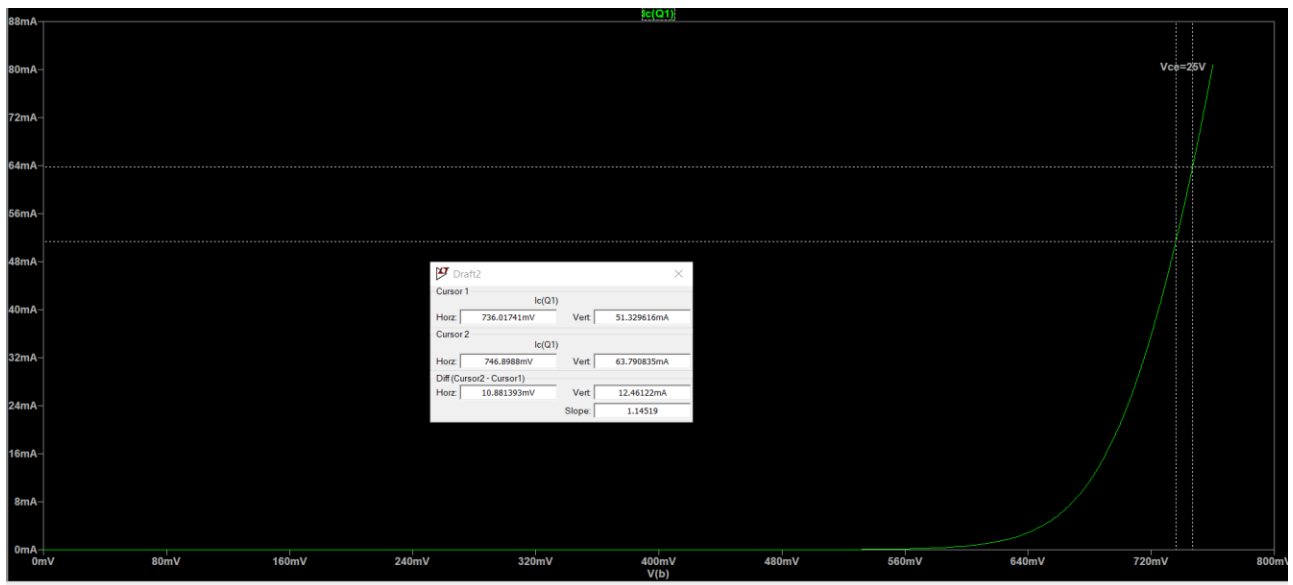
I_C vs V_{BE}



Here $V_{CC}=5V$ and $\Delta I_C = 7.869mA$, $\Delta V_{BE} = 10.88mV$ $g_{m1} = \Delta I_C / \Delta V_{BE} = 723.188 \text{ mA/V}$



Here $V_{CC}=15V$ and $\Delta I_C = 10.848mA$, $\Delta V_{BE} = 10.88139mV$ $g_{m2} = \Delta I_C / \Delta V_{BE} = 996.9 mA/V$



Here $V_{CC}=25V$ and $\Delta I_C = 12.4612mA$, $\Delta V_{BE} = 10.881393mV$ $g_{m3} = \Delta I_C / \Delta V_{BE} = 1145.2mA/V$

CONCLUSION:

In 1st part (input characteristics), we got the Base-Emitter Resistance values as

$R_{BE1}=466\text{ohm}$ for $V_{CC}=0V$

$R_{BE2}= 533.8\text{ohm}$ for $V_{CC}=10V$

$R_{BE3}= 578\text{ohm}$ for $V_{CC}=20V$

So, from this we understand that as we increase the constant V_{CC} value the Base-Emitter resistance increases which indicates slope($1/R_{BE}$) decreases in the linear part of the graph. So, the graph with higher V_{CC} will be less steep.

In Output Characteristics, we got the output resistance and early voltage values as

$R_{O1}= 4493.55\text{ohm}$, $V_{A1}=51.97V$ for $V_{BB1}=2V$

$R_{O2}= 1326.63\text{ohm}$, $V_{A2}=51.89V$ for $V_{BB1}=6V$

$R_{O3}= 850.71\text{ohm}$, $V_{A3}=51.86V$ for $V_{BB1}=10V$

As the constant V_{BB} is increasing output resistance is decreasing. We also have relation that $R_O= \Delta V_{CE}/\Delta I_C= V_A/I_C$. We can clearly observe that the early voltages for different values of V_{BB} are almost same and equal to **$V_A\approx 52V$** .

So this means that when the linear part of the plots are extended they cut the –ve x-axis at same point.

Finally, in transfer characteristics, we got the transconductance values as

$g_{m1}= 723.188 \text{ mA/V}$ for $V_{CC}=5V$

$g_{m2}= 996.9\text{mA/V}$ for $V_{CC}=15V$

$g_{m3}= 1145.2\text{mA/V}$ for $V_{CC}=25V$

We can observe that as we increase the constant V_{CC} the transconductance increases which implies graph with higher V_{CC} is more steeper and we can verify it from the graph below.

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